

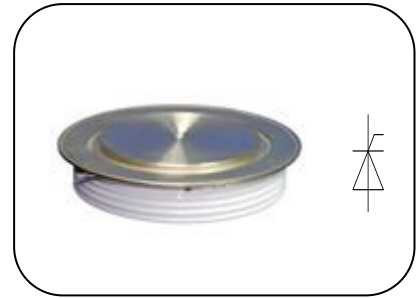
**Features**

- Center amplifying gate
- Metal case with ceramic insulator
- Low on-state and switching losses

**Typical Applications**

- AC controllers
- DC and AC motor control
- Controlled rectifiers

$I_{T(AV)}$       **3227 A**  
 $V_{DRM}/V_{RRM}$     **1100-1800V**  
 $I_{TSM}$             **60 kA**  
 $I^2t$                 **18000 10<sup>3</sup>A<sup>2</sup>S**



SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T <sub>j</sub> (°C)	VALUE			UNIT
				Min	Type	Max	
I <sub>T(AV)</sub>	Mean on-state current	180° half sine wave 50Hz Double side cooled, T <sub>C</sub> =70°C	125			3227	A
V <sub>DRM</sub> V <sub>RRM</sub>	Repetitive peak off-state voltage Repetitive peak reverse voltage	tp=10ms	125	1100		1800	V
I <sub>DRM</sub> I <sub>RRM</sub>	Repetitive peak current	at V <sub>DRM</sub> at V <sub>RRM</sub>	125			250	mA
I <sub>TSM</sub>	Surge on-state current	10ms half sine wave ,V <sub>R</sub> =0.6V <sub>RRM</sub>	125			60	kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing coordination					18000	A <sup>2</sup> s*10 <sup>3</sup>
V <sub>TO</sub>	Threshold voltage		125			0.99	V
r <sub>T</sub>	On-state slope resistance					0.09	mΩ
V <sub>TM</sub>	Peak on-state voltage	I <sub>TM</sub> =5000A, F=40kN	25			1.60	V
dv/dt	Critical rate of rise of off-state voltage	V <sub>DM</sub> =0.67V <sub>DRM</sub>	125			1000	V/μs
di/dt	Critical rate of rise of on-state current	V <sub>DM</sub> = 67%V <sub>DRM</sub> to6000A, Gate pulse t <sub>r</sub> ≤0.5μs I <sub>GM</sub> =1.5A	125			250	A/μs
Q <sub>rr</sub>	Recovery charge	I <sub>TM</sub> =2000A ,tp=2000μs, di/dt=-20A/μs, V <sub>R</sub> =50V	125		2500		μC
I <sub>GT</sub>	Gate trigger current	V <sub>A</sub> =12V, I <sub>A</sub> =1A	25	40		300	mA
V <sub>GT</sub>	Gate trigger voltage			0.8		3.0	V
I <sub>H</sub>	Holding current			20		300	mA
V <sub>GD</sub>	Non-trigger gate voltage	V <sub>DM</sub> =67%V <sub>DRM</sub>	125			0.3	V
R <sub>th(j-c)</sub>	Thermal resistance Junction to case	DC· double side cooled Clamping force 40.0kN				0.010	°C /W
R <sub>th(c-h)</sub>	Thermal resistance case to heatsink					0.003	
F <sub>m</sub>	Mounting force			35		47	kN
T <sub>stg</sub>	Stored temperature			-40		140	°C
W <sub>t</sub>	Weight				1100		g
Outline	P17						

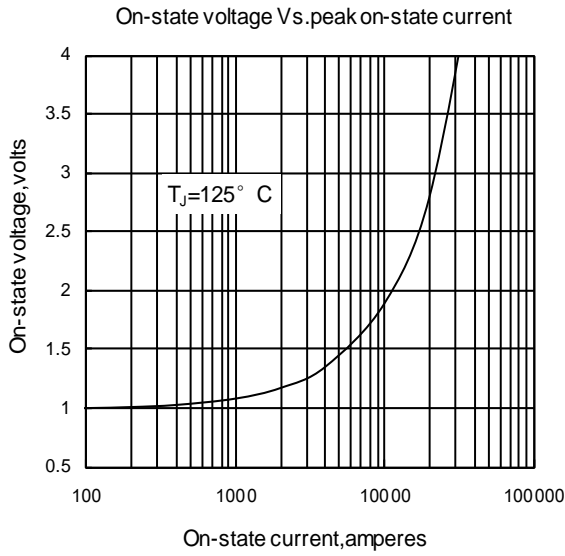


Fig1

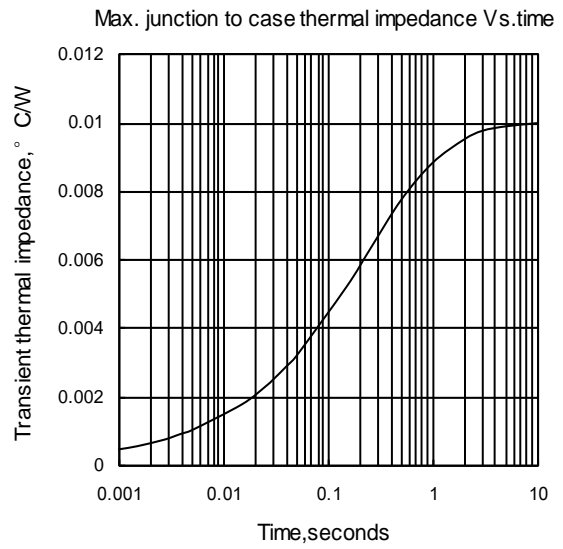


Fig2

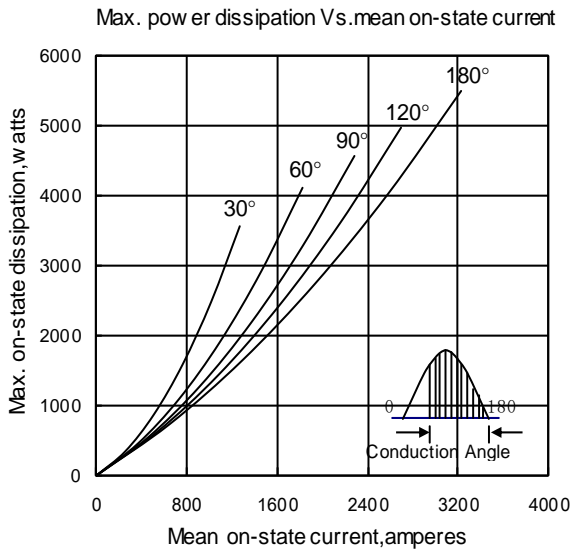


Fig3

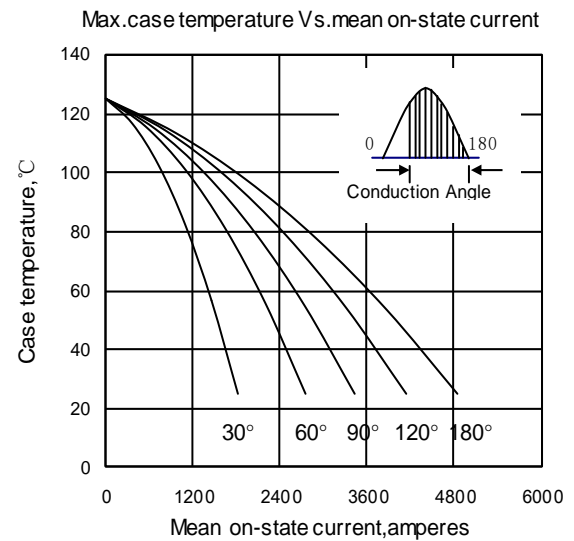


Fig4

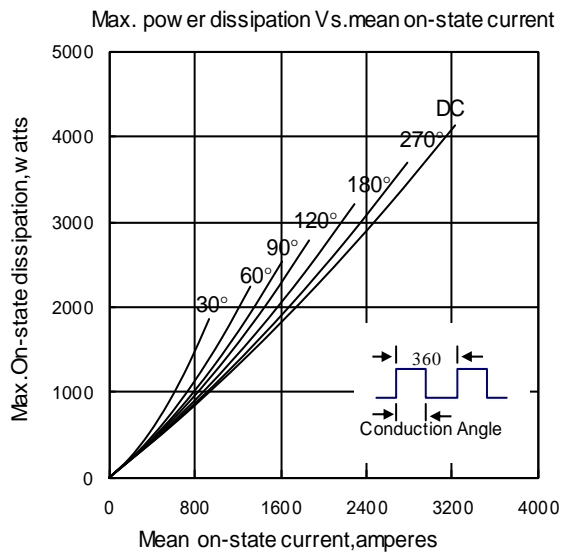


Fig5

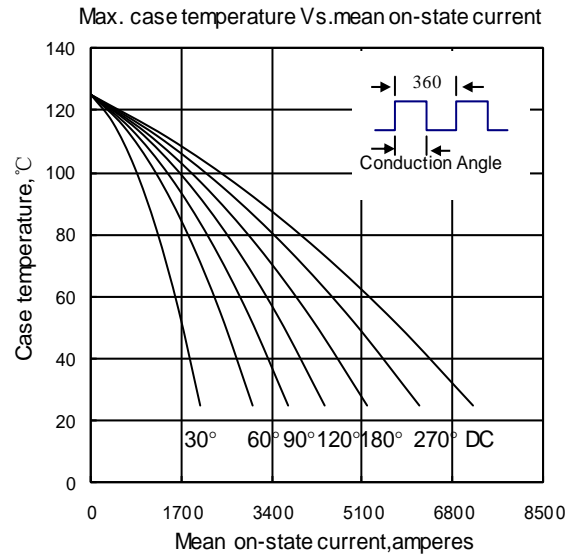


Fig6

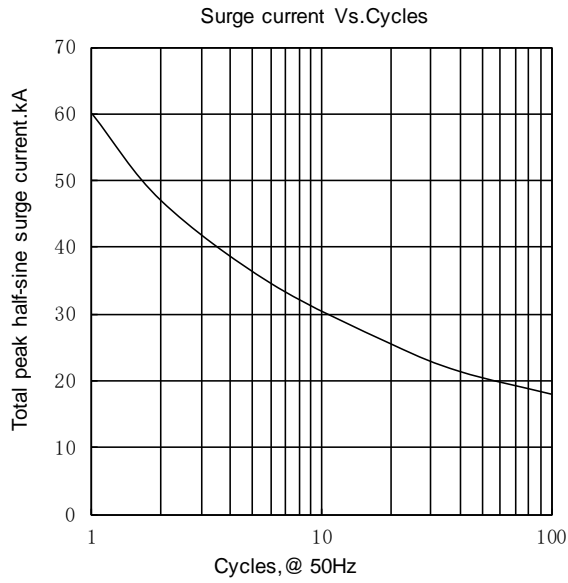


Fig.7

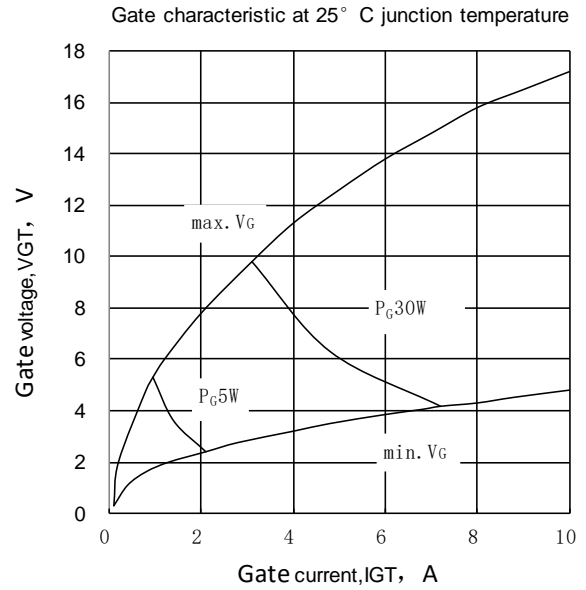


Fig.8

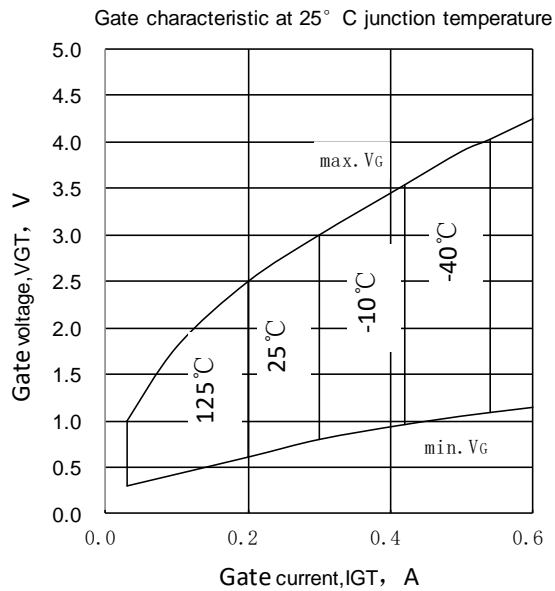
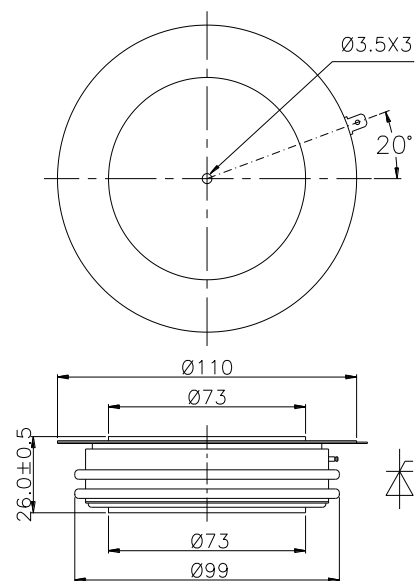


Fig.9



Nlps reserves the right to change specifications without notice.